

Data Sheet January 2000 File Number 3684.2

15A, 400V - 600V Hyperfast Dual Diodes

The RHRG1540CC and RHRG1560CC are hyperfast dual diodes with soft recovery characteristics (t_{rr} < 35ns). They have half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

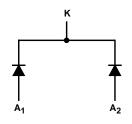
Formerly developmental type TA49061.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRG1540CC	TO-247	RHRG1540C
RHRG1560CC	TO-247	RHRG1560C

NOTE: When ordering, use the entire part number.

Symbol



Features

•	Hyperfast with Soft Recovery < 35ns
•	Operating Temperature
•	Reverse Voltage Up To
•	Avalanche Energy Rated

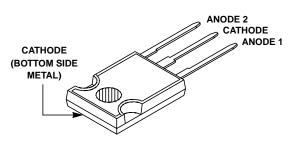
Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC STYLE TO-247



Absolute Maximum Ratings (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RHRG1540CC	RHRG1560CC	UNITS
Peak Repetitive Reverse VoltageV _{RRM}	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking Voltage	400	600	V
Average Rectified Forward Current	15	15	Α
Repetitive Peak Surge Current	30	30	Α
Nonrepetitive Peak Surge Current	200	200	Α
Maximum Power Dissipation	100	100	W
Avalanche Energy (See Figure 10 and 11)	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	°C

RHRG1540CC, RHRG1560CC

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

	TEST CONDITION	RHRG1540CC		RHRG1560CC				
SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 15A	-	-	2.1	-	-	2.1	V
	I _F = 15A, T _C = 150 ^o C	-	-	1.7	-	-	1.7	V
I _R	V _R = 400V	-	-	100	-	-	-	μА
	V _R = 600V	-	-	-	-	-	100	μА
	$V_R = 400V, T_C = 150^{\circ}C$	-	-	500	-	-	-	μА
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	500	μА
t _{rr}	$I_F = 1A$, $dI_F/dt = 100A/\mu s$	-	-	35	-	-	35	ns
	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	-	-	40	-	-	40	ns
t _a	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	-	20	-	-	20	-	ns
t _b	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	-	15	-	-	15	-	ns
Q _{RR}	I _F = 15A, dI _F /dt = 100A/μs	-	40	-	-	40	-	nC
СЈ	V _R = 10V, I _F = 0A	-	60	-	-	60	-	pF
$R_{\theta JC}$		-	-	1.5	-	-	1.5	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse Recovery Charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

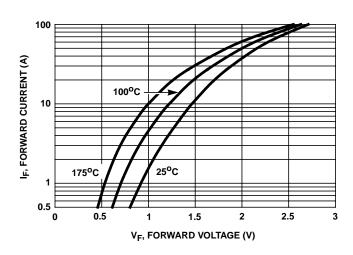


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

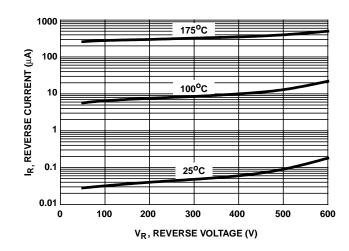


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

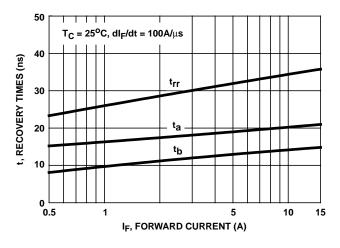


FIGURE 3. $t_{\rm rr}, t_{\rm a}$ and $t_{\rm b}$ curves vs forward current

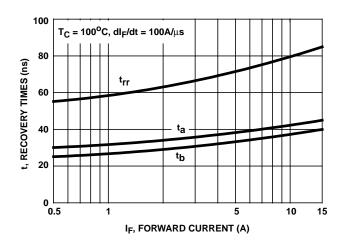


FIGURE 4. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

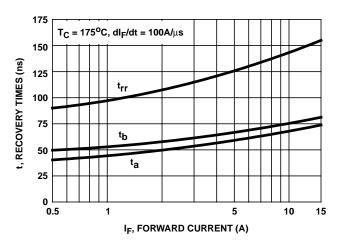


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

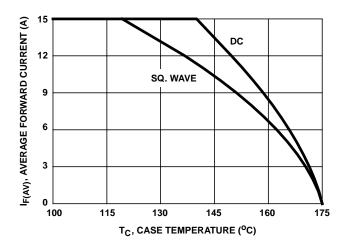


FIGURE 6. CURRENT DERATING CURVE

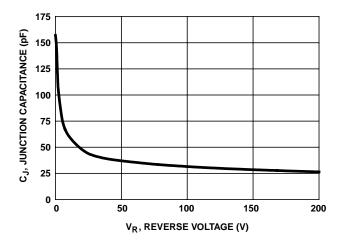


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

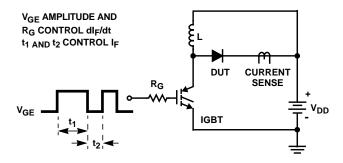


FIGURE 8. t_{rr} TEST CIRCUIT

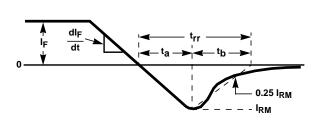


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

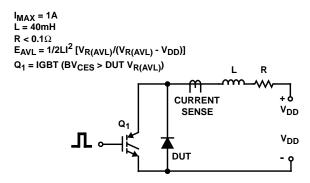


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

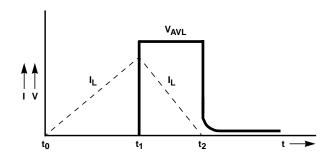


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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